onsemi

Small Signal Diode

1N5282

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
V _{RRM}	Maximum Repetitive Reverse Voltage	80	V
I _{F(AV)}	Average Rectified Forward Current	200	mA
I _{FSM}	Non–repetitive Peak Forward Surge Current Pulse Width = 1.0 s Pulse Width = 1.0 μs	1.0 4.0	A A
T _{STG}	Storage Temperature Range	-65 to +200	°C
ТJ	Operating Junction Temperature	175	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. These ratings are based on a maximum junction temperature of 200°C.

These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

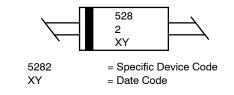
THERMAL CHARACTERISTICS

Symbol	Parameter	Value	Unit
PD	Power Dissipation	500	mV
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	300	°C/W



AXIAL LEAD (DO-35) CASE 017AG (Color Band Denotes Cathode)

MARKING DIAGRAM



ORDERING INFORMATION

Device	Package	Shipping [†]		
1N5282	AXIAL LEAD (Pb-Free, Halide Free)	5000 Units / Bulk		
1N5282TR		10000 / Tape & Reel		

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, <u>BRD8011/D</u>.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

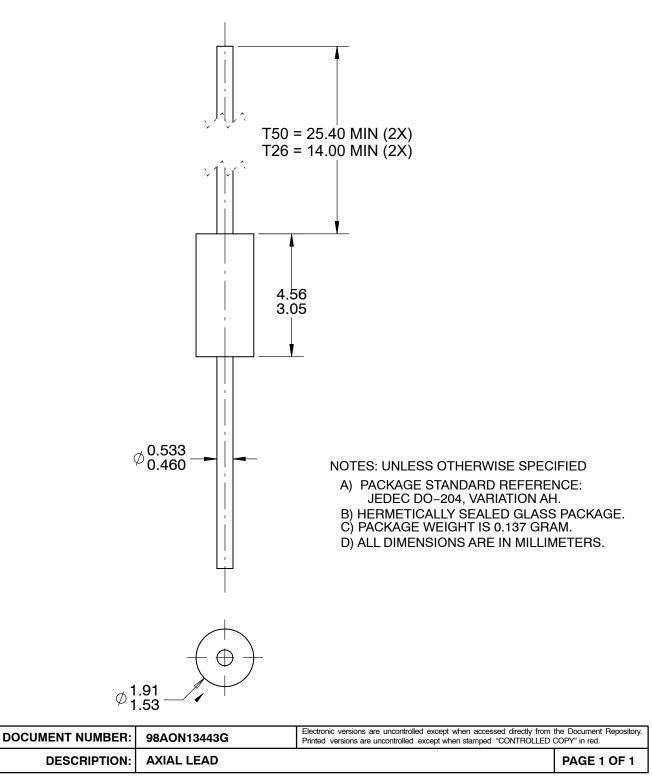
Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
V _R	Breakdown Voltage	I _R = 5 μA	80	-	-	V
V _F	Forward Voltage	$ I_F = 0.1 \text{ mA} \\ I_F = 1.0 \text{ mA} \\ I_F = 10 \text{ mA} \\ I_F = 100 \text{ mA} \\ I_F = 300 \text{ mA} \\ I_F = 500 \text{ mA} $	0.45 0.55 0.67 0.80 0.92 1.05	- - - - -	0.49 0.60 0.725 0.90 1.1 1.3	V
I _R	Reverse Current	$V_{R} = 55 V$ $V_{R} = 55 V$, $T_{A} = 150^{\circ}C$	-	_	100 100	nA μA
C _T	Total Capacitance	V _R = 0, f = 1.0 MHz	-	-	2.5	pF
t _{rr1}	Reverse Recovery Time	$I_F = I_R = 10 \text{ mA}, R_L = 100 \Omega$ Irr = 1.0 mA	-	-	4	ns
t _{rr2}	Reverse Recovery Time	I_F = I_R = 200 mA, R_L = 100 Ω Irr = 20 mA	-	-	4	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.



AXIAL LEAD CASE 017AG ISSUE O

DATE 31 AUG 2016



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